

Shenzhen Lingxing Microelectronics Technology Co., Ltd. 版次: B1 编号: 24C16-LX-A016

24C16 (LX) I²C-Compatible Serial E²PROM

Product Specification

Specification Revision History :

Version	Data	Description
2022-01-A4	2022-01	New-made

Address:808, West Building, Feiyada Building, No. 163, Zhenhua Road, Huahang Community, Huaqiang North Street, Futian District, Shenzhen P.C: 518000 www.lingxingic.com 第1页 共17页 VER: 2022-01-A3



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1, General Description

The 24C16 is 16-Kbit I²C-compatible Serial EEPROM (Electrically Erasable Programmable Memory) device. It contains a memory array of 2048×8 bits, which is organized in 16 -byte per page. The device is used in low-voltage and low-power systems.

Features:

- Single Supply Voltage and High Speed Minimum operating voltage down to 1.7V
 - 1 MHz clock from 2.5V to 5.5V
 - 400kHz clock from 1.7V to 2.5V
- Low power CMOS technology Read current 1.0mA, maximum Write current 2.0mA, maximum
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- Sequential & Random Read Features
- Page Write Modes, Partial Page Writes Allowed
- Write protect of the whole memory array
- Self-timed Write Cycle (5ms maximum)
- High Reliability
 - Endurance: > 1 Million Write Cycles Data Retention: > 100 Years
- LATCH UP Capability: +/- 200mA
- Package: DIP8, SOP8, TSSOP8



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Ordering Information:

Tube packing specifications:

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
24C16(LX)	DIP8	24C16	50 PCS/tube	40 tube/box	2000 PCS/box	Dimensions of plastic enclosure: 9.2mm×6.4mm Pin spacing: 2.54mm
24C16(LX)	SOP8	24C16	100 PCS/tube	100 tube/box	10000 PCS/box	Dimensions of plastic enclosure: 4.9mm×3.9mm Pin spacing: 1.27mm

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
24C16(LX)	SOP8	24C16	4000PCS/reel	8000PCS/box	Dimensions of plastic enclosure: 4.9mm×3.9mm Pin spacing:1.27mm
24C16(LX)	TSSOP8	24C16	3000PCS/reel	3000PCS/box	Dimensions of plastic enclosure: 3.0mm×3.0mm Pin spacing:0.65mm

Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.



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2 Block Diagram And Pin Description

2.1 Slock Diagram



2.2 , Pin Configurations



2.3 Pin Description

Pin No.	Pin Name	Description
1	A0	Not connected
2	A1	Not connected
3	A2	Not connected
4	GND	Ground
5	SDA	Serial Data Input and Serial Data Output
6	SCL	Serial Clock Input
7	WP	Write Control, Low Enable Write
8	Vcc	Power



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2.4 > Pin Descriptions

Serial Clock (SCL): The SCL input is used to positive-edge clock data in and negative-edge clock data out of each device.

Serial Data (SDA): The SDA pin is bidirectional for serial data transfer. This pin is open drain driven and may be wire-Ored with any number of other open-drain or open-collector devices.

Device Addresses (A2, A1, A0): The A2, A1 and A0 pins are device address inputs. Typically, the A2, A1 and A0 pins are for hardware addressing and a total of 8 devices can be connected on a single bus system. If these pins are left floating, the A2, A1 and A0 pins will be internally pulled down to GND.

Write Control (WP): The Write Control input, when WP is connected directly to V_{CC} , all write operations to the memory are inhibited. When connected to GND, allows normal write operations. If the pin is left floating, the WP pin will be internally pulled down to GND.

3、Electrical Parameter

3.1 、 Absolute Maximum Ratings

(T_{amb}=25°C, All voltage referenced to GND, unless otherwise specified)

Characteristic	Symbol	Condi	tions	Value	Unit														
Power Supply Voltage	Vcc	-		6.25	V														
Voltage on Any Pin with Respect to Ground	V	_		_				_										-1.0 to +7.0	V
DC Output Current	Ι			-		-		5.0	mA										
Input/Output Capacitance (SDA)	C _{I/O}	f=1.0MHz, V _{CC} =	=5V,V _{I/O} =GND	8	pF														
Input Capacitance (E0,E1,E2,WP,SCL)	C _{IN}	f=1.0MHz,V _{CC} =	=5V,V _{IN} =GND	6	pF														
Operating Temperature	T _{amb}	-		-40 to +85	°C														
Storage Temperature	T _{stg}	-		-65 to +150	°C														
Soldering Temperature	T-	100	DIP	245	ŝ														
soluering Temperature	ΙL	108	SOP	250															

Notes:

[1] This parameter is ensured by characterization not 100% tested

[2]Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.



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3.2 Selectrical Characteristics

3.2.1 DC Characteristics

 $(T_{amb}=-40^{\circ}C \text{ to } +85^{\circ}C, V_{CC}=+1.8V \text{ to } +5.5V, \text{ unless otherwise specified})$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	V _{CC}	-	1.7	-	5.5	V
Standby Current	Ich	Vcc=3.3V, T _{amb} = 85 °C	-	-	1.0	uA
Standby Current	180	$Vcc=5.5V, T_{amb}=85^{\circ}C$	-	-	3.0	uA
Supply Current	I _{CC1}	Vcc=5.5V, Read at 400Khz	-	-	1.0	mA
Supply Current	I _{CC2}	Vcc=5.5V,Write at 400Khz	-	-	2.0	mA
Input Leakage Current	I _{LI}	V _{IN} =V _{CC} or GND	-	0.10	1.0	μA
Output Leakage Current	ILO	V _{OUT} =V _{CC} or GND	-	0.05	1.0	μA
Input Low Level	V _{IL}	-	-0.6	-	0.3V _{CC}	V
Input High Level	V _{IH}	-	$0.7 V_{CC}$	T	V _{CC} +0.5	V
Output Low Level	V _{OL1}	V _{CC} =1.7V (SDA) I _{OL} =1.5 mA	-	-	0.2	v
Output Low Level	V _{OL2}	V _{CC} =3.0V (SDA) I _{OL} =2.1 mA	-	-	0.4	V

Notes: [1] This parameter is ensured by characterization not 100% tested 3.2.2 AC Characteristics

(T_{amb}=-40°C to +85°C, V_{CC}=+1.8V to +5.5V, C_L=1 TTL Gate and 100pF, unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
		V _{CC} =1.7V	-	-	400	
Clock Frequency,	f _{SCL}	V _{CC} =2.7V	-	-	1000	kHz
SCL		V _{CC} =5.0V	-	-	1000	
Classic Decise Wildel		V _{CC} =1.7V	1.3	-	-	
Low	t _{LOW}	V _{CC} =2.7V	0.4	-	-	us
LOW		V _{CC} =5.0V	0.4	-	-	
Cloals Dulas Wedth		V _{CC} =1.7V	0.6	-	-	
Clock Pulse width High	t _{HIGH}	V _{CC} =2.7V	0.4	-	-	us
Ingh		V _{CC} =5.0V	0.4	-	-	
Noise Cummercian		V _{CC} =1.7V	-	-	100	
Time	tı	V _{CC} =2.7V	I	-	50	ns
Time		V _{CC} =5.0V	-	-	50	
Clash Low to Data	t _{AA}	V _{CC} =1.7V	0.05	-	0.9	us
Out Valid		$V_{CC}=2.7V$	0.05	-	0.55	
Out valid		V _{CC} =5.0V	0.05	-	0.55	
Time the bus must be		V _{CC} =1.7V	1.3	-	-	
free before a new	t _{BUF}	V _{CC} =2.7V	0.5	-	-	us
transmission can start		V _{CC} =5.0V	0.5	-	-	
		V _{CC} =1.7V	0.6	-	-	
Start Hold Time	t _{HD.STA}	V _{CC} =2.7V	0.25	-	-	us
		$V_{CC}=5.0V$	0.25	-	-	
		V _{CC} =1.7V	0.6	-	-	
Start Setup Time	t _{SU.STA}	V _{CC} =2.7V	0.25	-	-	us
		V _{CC} =5.0V	0.25	-	-	

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		V _{CC} =1.7V	0	-	-	
Data In Hold Time	t _{HD.D}	V _{CC} =2.7V	0	-	-	us
		V _{CC} =5.0V	0	-	-	
		V _{CC} =1.7V	100	-	-	
Data In Setup Time	t _{SU.D}	V _{CC} =2.7V	100	-	-	ns
		V _{CC} =5.0V	100	-	-	
		V _{CC} =1.7V	-	-	300	
Inputs Rise Time ^[1]	t _R	V _{CC} =2.7V	-	-	300	ns
		V _{CC} =5.0V	-	-	300	
		V _{CC} =1.7V	-	-	300	
Inputs Fall Time ^[1]	t _F	V _{CC} =2.7V	-	-	300	ns
		V _{CC} =5.0V	-	-	100	
		V _{CC} =1.7V	0.6	-	-	
Stop Setup Time	t _{SU.STO}	V _{CC} =2.7V	0.25	-	-	us
		V _{CC} =5.0V	0.25	-	-	
		V _{CC} =1.7V	50	-	-	
Data Out Hold Time	t _{DH}	V _{CC} =2.7V	50	-	-	ns
		V _{CC} =5.0V	50	-	-	
		V _{CC} =1.7V	1.2	-	-	
WP pin Setup Time	t _{SU.WP}	V _{CC} =2.7V	0.6	-	-	us
		V _{CC} =5.0V	0.6		-	
		V _{CC} =1.7V	1.2	-	-	
WP pin Hold Time	t _{HD.WP}	V _{CC} =2.7V	0.6	-	-	us
		V _{CC} =5.0V	0.6	-	-	
		V _{CC} =1.7V	-	-	5	
Write Cycle Time	t _{WR}	V _{CC} =2.7V	-	-	5	ms
		V _{CC} =5.0V	-	-	5	
Endurance	EDR	3.3V, Page mode	1,000,000	-	-	Write cycles
Data retention	DRET	-	100	-	-	Years

Note: [1] This parameter is ensured by characterization and is not 100% tested



4. Function Description

4.1 Device Operation

4.1.1 Data Input

The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see to Figure 4-1). Data changes during SCL high periods will indicate a start or stop condition as defined below.



Figure 4-1

4.1.2 Start Condition

A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see to Figure 4-2).

4.1.3 Stop Condition

A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the 24C16 in a standby power mode (see Figure 4-2)





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4.1.4 、 Acknowledge (ACK)

All addresses and data words are serially transmitted to and from the 24C16 in 8-bit words. The 24C16 sends a "0" to acknowledge that it has received each word. This happens during the ninth clock cycle(see to Figure 4-3).



4.1.5 Standby Mode

The 24C16 features a low-power standby mode which is enabled: (a) after a fresh power up, (b) after receiving a STOP bit in read mode, and (c) after completing a self-time internal programming operation.

4.1.6 Soft Reset

After an interruption in protocol, power loss or system reset, any two-wire part can be reset by following these steps: (a) Create a start condition, (b) Clock nine cycles, and (c) create another start bit followed by stop bit condition, as shown below. The device is ready for the next communication after the above steps have been completed(see to Figure 4-4).



Figure 4-4



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4.1.7 Bus Timing(see to Figure 4-5).



4.1.8 Vrite Cycle Timing(see to Figure 4-6)



Figure 4-6

4.2 Device Addressing

The 24C16 requires an 8-bit device address word following a start condition to enable the chip for a read or write operation. The device address word consists of a mandatory one-zero sequence for the first four most-significant bits.

MSB

MSB							LSB
1	0	1	0	A2 (B10)	A1 (B9)	A0 (B8)	R/W

The A2, A1 and A0 device address bits can be used as the upper three bits of the data word address.. The A2, A1 and A0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are floating.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low. Upon a compare of the device address, the Chip will output a zero. If a compare is not made, the device will return to a standby state.

MSB							LSB
B7	B6	B5	B4	B3	B2	B1	B0

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4.3 Data Security

24C16 has a hardware data protection scheme that allows the user to write protect the whole memory when the WP pin is at Vcc.

4.4 Write Operations

4.4.1、Byte Write

A write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the 24C16 will again respond with a "0" and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the 24C16 will output a "0" and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. And then the 24C16 enters an internally timed write cycle, all inputs are disabled during this write cycle and the 24C16 will not respond until the write is complete (see Figure 4-7).



4.4.2 **Page Write**

A page write is initiated the same as a byte write, but the master does not send a stop condition after the first data word is clocked in. Instead, after the 24C16 acknowledges receipt of the first data word, the master can transmit more data words. The 24C16 will respond with a "0" after each data word received. The microcontroller must terminate the page write sequence with a stop condition (see Figure 4-8).



Figure 4-8

The lower four bits of the data word address are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 16 data words are transmitted to the 24C16, the data word



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address will roll-over, and previous data will be overwritten. The address roll-over during write is from the last byte of the current page to the first byte of the same page.

4.4.3 \ Acknowledge Polling

Once the internally timed write cycle has started and the 24C16 inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the 24C16 respond with a "0", allowing the read or write sequence to continue.

4.5 、 Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to "1". There are three read operations: Current Address Read; Random Address Read and Sequential Read.

4.5.1 、 Current Address Read

The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address roll-over during read is from the last byte of the last memory page to the first byte of the first page.

Once the device address with the read/write select bit set to "1" is clocked in and acknowledged by the 24C16, the current address data word is serially clocked out. The microcontroller does not respond with an input "0" but does generate a following stop condition (see Figure 4-9).



4.5.2 Random Read

A Random Read requires a "dummy" byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the 24C16, the microcontroller must generate another start condition. The microcontroller now initiates a Current Address Read by sending a device address with the read/write select bit high. The 24C16 acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a "0" but does generate a following stop condition (see Figure 4-10).

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4.4.3, Sequential Read

Sequential Reads are initiated by either a Current Address Read or a Random Address Read. After the microcontroller receives a data word, it responds with acknowledge. As long as the 24C16 receives acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will roll-over and the Sequential Read will continue. The Sequential Read operation is terminated when the microcontroller does not respond with a "0" but does generate a following stop condition (see Figure 4-11)







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5, Package Information

5.1 \ DIP8







Growhal	Dimension I	n Millimeters	Dimension In Inches		
Symbol	Min	Max	Min	Max	
А	3.610	4.310	0.142	0.170	
A1	0.510		0.020		
A2	3.100	3.600	0.122	0.142	
В	0.360	0.560	0.014	0.022	
B1	1.524(TYP)		0.060(TYP)		
С	0.200	0.360	0.008	0.014	
D	9.000	9.500	0.354	0.374	
Е	6.100	6.600	0.240	0.260	
E1	7.620	(TYP)	0.300	(TYP)	
e	2.540(TYP)		0.100	(TYP)	
L	3.000	3.600	0.118	0.142	
E2	8.200	9.400	0.323	0.370	



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5.2 SOP8



Ch-al	Dimension In	n Millimeters	Dimension In Inches			
Symbol	Min	Max	Min	Max		
А	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
В	0.330	0.510	0.013	0.020		
С	0.170	0.250	0.007	0.010		
D	4.780	5.000	0.188	0.197		
Е	3.800	4.000	0.150	0.157		
E1	5.800	6.300	0.228	0.248		
e	1.270(TYP)		0.050(TYP)			
L	L 0.400		0.016	0.050		
θ 0°		8°	0°	8°		



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5.3 **TSSOP8**



Semihal	Dimension I	n Millimeters	Dimension In Inches		
Symbol	Min	Max	Min	Max	
А	1.1 MA	X TYP	0.043 MAX TYP		
A1	0.050	0.150	0.002	0.006	
A2	0.850	0.950	0.033	0.037	
В	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	0.008	
D	2.900	3.100	0.114	0.122	
Е	4.300	4.500	0.169	0.177	
E1	6.200	6.600	0.224	0.260	
e	0.650	(TYP)	0.026 (TYP)		
L	0.500	0.700	0.020	0.028	
θ	1°	7°	1°	7°	

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6. Statements And Notes

6.1 、 The name and content of Hazardous substances or Elements in the product

	Hazardous substances or Elements									
Part name	Lead and lead compou nds	Mercur y and mercur y compo unds	Cadm ium and cadmi um comp ounds	Hexaval ent chromiu m compoun ds	Polybro minated biphenyl s	Polybro minate d biphen yl ethers	Dibutyl phthala te	Butylbe nzyl phthala te	Di-2-et hylhex yl phthala te	Diisobu tyl phthala te
Lead frame	0	0	0	0	0	0	0	0	0	0
Plastic resin	0	0	0	0	0	0	0	0	0	0
Chip	0	0	0	0	0	0	0	0	0	0
The lead	0	0	0	0	0	0	0	0	0	0
Plastic sheet installed	0	0	0	0	0	0	0	0	0	0
explanatio n	 o: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. x: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements 									

6.2 Notion

Recommended carefully reading this information before the use of this product;

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